### **High Performance MEMS VCXO**

### Advanced information



### ■ Features, Benefits and Applications

- Any frequency between 1 MHz and 80 MHz with 6 decimal places of accuracy
- 100% pin-to-pin compatible with and direct replacement of quartz based VCXO
- Widest pull range options: ±25, ±50, ±100, ±150, ±200, ±400, ±800, ±1600 PPM
- Superior pull range linearity of <= 1%, 10 times better than quartz
- LVCMOS/LVTTL compatible output
- Typical tuning voltage: 0 V to Vdd
- Three industry-standard packages: 3.2 mm x2.5 mm (4-pin), 5.0 mm x 3.2 mm (6-pin), 7.0 mm x 5.0 mm (6-pin)
- Outstanding siicon reliability of 2 FIT (10x improvement over quartz-based devices)
- Ultra short lead time
- Ideal for telecom clock synchronization, instrumentation, low bandwidth analog PLL, jitter cleaner, clock recovery, audio, video, FPGA, broadband and networking

### ■ Specifications

### **Electrical Characteristics**

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
Output Frequency Range	f	1	-	80	MHz		
Frequency Stability	F_stab	-10	-	+10	PPM	Inclusive of initial tolerance (F_init), operating temperature,	
		-25	-	+25	PPM	power, supply voltage change, load change	
		-50	=	+50	PPM	Select stability option in part number ordering (see back page)	
Operating Temperature Range	T_use	-20	-	+70	°C	Extended Commercial	
		-40	-	+85	°C	Industrial	
Supply Voltage	Vdd	1.71	1.8	1.89	V		
		2.25	2.5	2.75	V		
		2.52	2.8	3.08	V		
		2.97	3.3	3.63	V		
Pull Range <sup>[1,2]</sup>	PR	±25	, ±50, ±100,±	150,	PPM		
		±200, ±400, ±800, ±1600					
Upper Control Voltage	VC_U	1.62	-	1.7	V	Vdd = 1.8 V, Voltage at which maximum deviation is guaranteed.	
		2.25	-	2.3	V	Vdd = 2.5 V, Voltage at which maximum deviation is guaranteed.	
	,	2.52	-	2.6	V	Vdd = 2.8 V, Voltage at which maximum deviation is guaranteed.	
	,	3	-	3.1	V	Vdd = 3.3 V, Voltage at which maximum deviation is guaranteed.	
Lower Control Voltage	VC_L	0	-	0.1	V	Voltage at which maximum deviation is guaranteed.	
Linearity	Lin	-	-	1	%		
Frequency Change Polarity	1		Positive slope	е	-		
Control Voltage Bandwidth(-3dB)	V_BW	ı	8	-	kHz	Contact SiTime for 16 kHz bandwidth	
		2.97	3.3	3.63	V		
Current Consumption	ldd	-	29	33	mA	No load condition, f = 20 MHz, Vdd = 2.5 V, 2.8 V or 3.3 V	
		-	31	31	mA	No load condition, f = 20 MHz, Vdd = 1.8 V	
Standby Current	I_std	-	-	TBD	μΑ	ST = GND, All Vdd, Output is Weakly Pulled Down	
Duty Cycle	DC	45	-	55	%	All Vdds	
Rise/Fall Time	Tr, Tf	-	1.0	2.2	ns	Vdd = 1.8, 2.5, 2.8 or 3.3 V, 10% - 90% Vdd level	
Output Voltage High	VOH	90	-	-	%Vdd	IOH = TBD	
Output Voltage Low	VOL	-	-	10	%Vdd	IOL = TBD	
Output Load	Ld	1	-	15	pF		
Start-up Time	T_start	-	6	10	ms		
OE Enable/Disable Time	T_oe	ı	_	TBD	ms		
Resume Time	T_resume	-	-	10	ms	Measured from the time ST pin crosses 50% threshold	
RMS Period Jitter	T_jitt	-	1.7	-	ps	f = 10 MHz, all Vdds	
RMS Phase Jitter (random)	T_phj	-	0.51	-	ps	f = 10 MHz, Pull range = 100 PPM, Integration bandwidth = 12kHz to 20MHz, all Vdds	
Aging	F_aging	-	-	±5	PPM	10 years	

### Notes:

1. Absolute Pull Range (APR) is defined as the guaranteed pull range over temperature and voltage.

2. APR = pull range (PR) - frequency stability (F\_stab) - Aging (F\_aging)

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### ■ Specifications (Cont.)

### Pin Description Tables (4-pin device)

Pin #1 Functionality			
VIN			
0 - Vdd: produces voltage dependent frequency change			

Pin Map					
Pin	Connection				
1	VIN				
2	GND				
3	CLK				
4	Vdd				

### Pin Description Tables (6-pin device)

Pin #1 Functionality				
VIN				
0 - Vdd: produces voltage dependent frequency change				
Pin #2 Functionality				
NC				
H or L or Open: No effect on output frequency or other device functions				
OE				
H or Open <sup>[3]</sup> : specified frequency output				
L: output is high impedance				
ST				
H or Open <sup>[3]</sup> : specified frequency output				
L: output is low level (weak pull down). Oscillation stops				

ар
Connection
VIN
NC/OE/ST
GND
CLK
NC
Vdd

Absolute Maximur	n Datings

Attempted operation outside the absolute maximum ratings of the part may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

Parameter	Min.	Max.	Unit
Storage Temperature	-65	150	°C
Vdd	-0.5	4	V
Electrostatic Discharge	-	6000	V
Soldering Temperature (follow standard Pb free soldering guidelines)	-	260	°C
Number of Program Writes	-	1	NA
Program Retention over -40 to 125°C, Process, Vdd (0 to 3.65 V)	1,000+	-	years

### **Environmental Compliance**

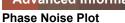
Parameter	Condition/Test Method		
Mechanical Shock	MIL-STD-883F, Method 2002; 50kG		
Mechanical Vibration	MIL-STD-883F, Method 2007; 70G		
Temperature Cycle	JESD22, Method A104		
Solderability	MIL-STD-883F, Method 2003		
Moisture Sensibility Level	MSL1 @ 260°C		

### Notes

3. In 1.8V mode, a resistor of <10 k $\Omega$  between OE pin and Vdd is required. SiTime recommends using pull-up resistors for other Vdd(s).

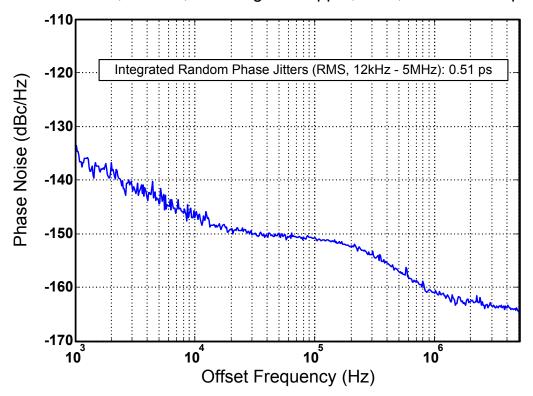
## High Performance MEMS VCXO



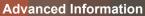




SiT3808, 10MHz, Pull range ±100ppm, 3.3V, LVCMOS output



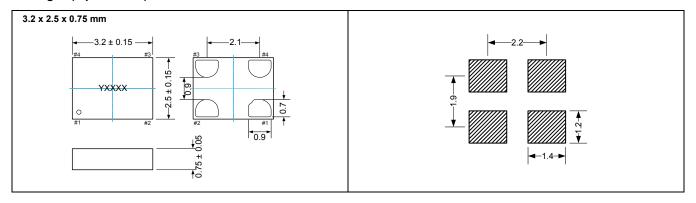
## **High Performance MEMS VCXO**



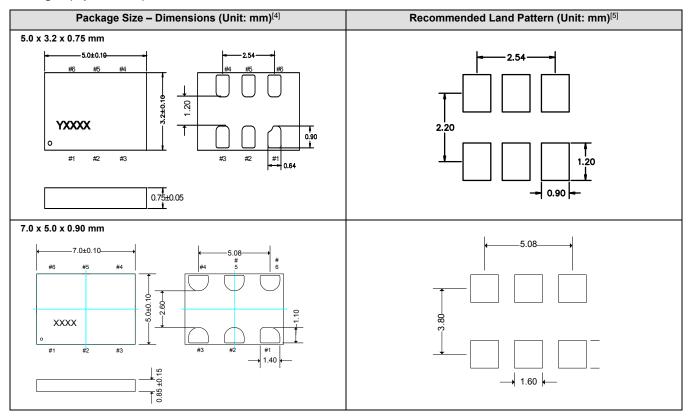


### ■ Dimensions and Land Patterns

### Packages (4-pin device)



### Packages (6-pin device)



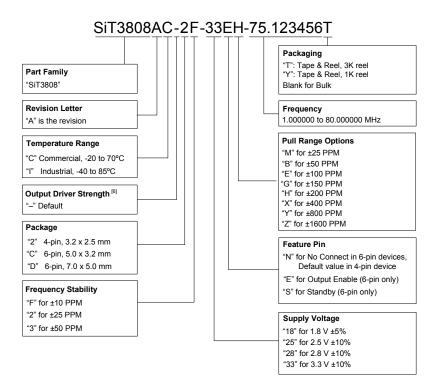
- Top marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.
  A capacitor of value 0.1 μF between Vdd and GND is recommended.

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■ Part No. Guide - How to Order



### **APR Definition**

Absolute pull range (APR) = Norminal pull range (PR) - frequency stability (F\_stab) - Aging (F\_aging)

### **APR Table**

	Frequency Stability			
Nominal Pull Range	± 10	± 25	±50	
	APR (PPM)			
± 25	± 10	_	_	
± 50	± 35	± 20	_	
± 100	± 85	± 70	± 45	
± 150	± 135	± 120	± 95	
± 200	± 185	± 170	± 145	
± 400	± 385	± 370	± 345	
± 800	± 785	± 770	± 745	
± 1600	± 1585	± 1570	± 1545	

### Note

6. Contact SiTime for different drive strength options for driving higher loads or reducing EM

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